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PN5432 **PN5433 PN5434** 



# **N-Channel Switch**

This device is designed for analog or digital switching applications where very low On Resistance is mandatory. Sourced from Process 58. See J108 for characteristics.

# **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
$V_{DG}$	Drain-Gate Voltage	25	V	
V <sub>GS</sub>	Gate-Source Voltage	-25	V	
I <sub>GF</sub>	Forward Gate Current	10	mA	
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C	

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- These ratings are based on a maximum junction temperature of 150 degrees C.
   These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

## **Thermal Characteristics**

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		PN5432 / 5433 / 5434	1
P <sub>D</sub>	Total Device Dissipation	350	mW
	Derate above 25°C	2.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W

# N-Channel Switch (continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
$V_{(BR)GSS}$	Gate-Source Breakdown Voltage	$I_G = 1.0  \mu A,  V_{DS} = 0$	-25		V
I <sub>GSS</sub>	Gate Reverse Current	$V_{GS} = 15 \text{ V}, V_{DS} = 0$ $V_{GS} = 15 \text{ V}, V_{DS} = 0, T_A = 150 \text{ °C}$		-200 -200	pA nA
$I_{D(off)}$	Drain Cutoff Leakage Voltage	$V_{GS} = 10 \text{ V}, V_{DS} = 5.0 \text{ V}$ $V_{GS} = 10 \text{ V}, V_{DS} = 5.0 \text{ V},$		-200	pA
V <sub>GS(off)</sub>	Gate-Source Cutoff Voltage	$T_A = 150 ^{\circ}\text{C}$ $V_{DS} = 5.0 \text{V},  I_D = 3.0 \text{nA}$ 5432	-4.0	-200 -10	nA V
¥ GS(0∏)	date double daten voltage	5433	-3.0	-9.0	v
		5434	-1.0	-4.0	V
	MATERIATION				
	RACTERISTICS  Zero-Gate Voltage Drain Current*	$V_{DS} = 15 \text{ V}, V_{GS} = 0$ 5432	150		mA
I <sub>DSS</sub>	Zero-Gate Voltage Drain Current	$v_{DS} = 15 \text{ v}, v_{GS} = 0$ 5432 5433	100		mA
		5434	30		mA
V <sub>DS(on)</sub>	Drain-Source On Voltage	$I_D = 10 \text{ mA}, V_{GS} = 0$ 5432		50	mV
		5433		70	mV
	Drain-Source On Resistance	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 5432	2.0	100 5.0	mV
r <sub>DS(on)</sub>	Diani-Source On Resistance	I <sub>D</sub> = 10 IIIA, V <sub>GS</sub> = 0 5432 5433	2.0	7.0	$\Omega$ $\Omega$
		5434		10	Ω
		$I_D = 0$ , $V_{GS} = 0$ , $f = 1.0 \text{ kHz}$			
		5432	2.0	5.0	Ω
		5433 5434		7.0 10	$\Omega$
SMALL SI	IGNAL CHARACTERISTICS			1	52
C <sub>iss</sub>	Input Capacitance	$V_{DS} = 0$ , $V_{GS} = 10$ V, $f = 1.0$ MHz		30	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	$V_{DS} = 0$ , $V_{GS} = 10$ V, $f = 1.0$ MHz		15	pF
SWITCHIN	NG CHARACTERISTICS		•		
t <sub>d</sub>	Delay Time	$V_{DD} = 1.5 \text{ V}, \ \ V_{GS(on)} = 0,$		4.0	ns
t <sub>r</sub>	Rise Time	$I_{D(on)} = 10 \text{ mA}$		1.0	ns
ts	Storage Time	$V_{GS(off)} = 12 V,$			
		$V_{DS(on)} = 50 \text{ mV}$ 5432		6.0	ns
		$V_{DS(on)} = 70 \text{ mV}$ 5433		6.0 6.0	ns ns
	Fall Time	V <sub>DS(on)</sub> = 100 mV 5434			
tf	Fall Time	$V_{GS(off)} = 12 \text{ V}$		30	ns

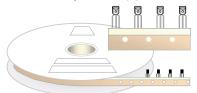
<sup>\*</sup>Pulse Test: Pulse Width  $\leq 300~\mu\text{s},~\text{Duty Cycle} \leq 2.0\%$ 

### **TO-92 Tape and Reel Data** FAIRCHILD SEMICONDUCTOR TM **TO-92 Packaging** Configuration: Figure 1.0 **TAPE and REEL OPTION** FSCINT Label sample See Fig 2.0 for various Reeling Styles CBVR/418019 **FSCINT** Label 5 Reels per Intermediate Box Customized F63TNR Label sample Label F63TNR LOT: CBVK741B019 QTY: 2000 FSID: PN222N Customized QTY1: QTY2: 375mm x 267mm x 375mm Intermediate Box TO-92 TNR/AMMO PACKING INFROMATION **AMMO PACK OPTION** See Fig 3.0 for 2 Ammo Packing Style Quantity EOL code **Pack Options** 2,000 D26Z 2,000 Е D27Z Ammo М 2,000 D74Z D75Z 2,000 **FSCINT** $\begin{array}{ll} \mbox{Unit weight} & = 0.22 \mbox{ gm} \\ \mbox{Reel weight with components} & = 1.04 \mbox{ kg} \\ \mbox{Ammo weight with components} & = 1.02 \mbox{ kg} \\ \mbox{Max quantity per intermediate box} & = 10,000 \mbox{ units} \end{array}$ Label 5 Ammo boxes per Intermediate Box 327mm x 158mm x 135mm Immediate Box Customized F63TNR Customized Label Label 333mm x 231mm x 183mm Intermediate Box (TO-92) BULK PACKING INFORMATION **BULK OPTION** See Bulk Packing DESCRIPTION QUANTITY Information table J18Z TO-18 OPTION STD Anti-static Bubble Sheets TO-5 OPTION STD NO LEAD CLIP 1.5 K / BOX J05Z **FSCINT Label** TO-92 STANDARD STRAIGHT FOR: PKG 92, 94 (NON PROELECTRON NO EOL NO LEADCLIP 2.0 K / BOX SERIES), 96 TO-92 STANDARD STRAIGHT FOR: PKG 94 (PROELECTRON SERIES BCXXX, BFXXX, BSRXXX), 97, 98 L34Z NO LEADCLIP 2.0 K / BOX 2000 units per 114mm x 102mm x 51mm EO70 box for std option Immediate Box 5 EO70 boxes per intermediate Box 530mm x 130mm x 83mm Customized Intermediate box Label FSCINT Label 10,000 units maximum per intermediate box for std option

## TO-92 Tape and Reel Data, continued

# **TO-92 Reeling Style Configuration:** Figure 2.0

## Machine Option "A" (H)



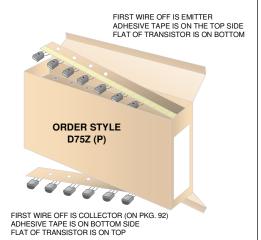
Style "A", D26Z, D70Z (s/h)

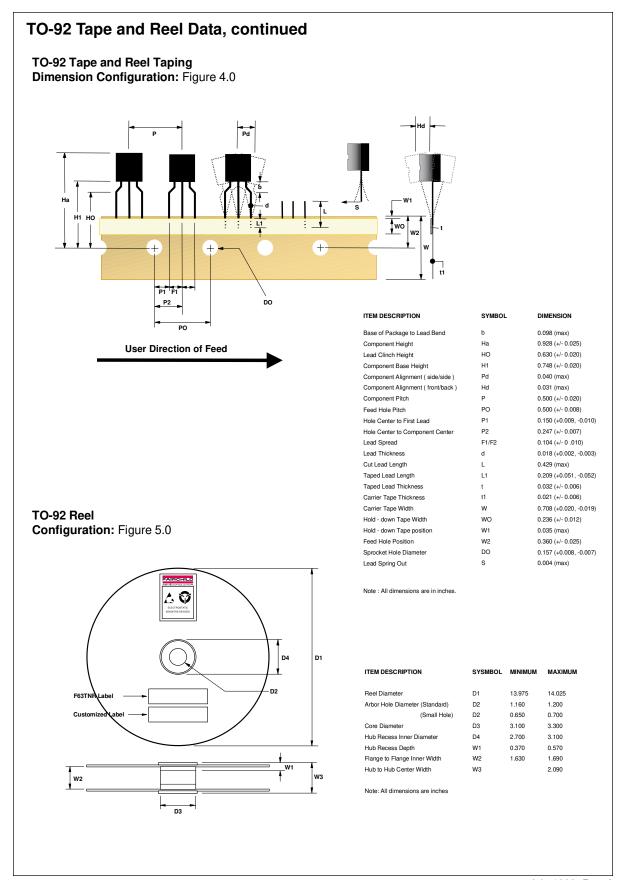
# Machine Option "E" (J)

Style "E", D27Z, D71Z (s/h)

# **TO-92 Radial Ammo Packaging Configuration:** Figure 3.0





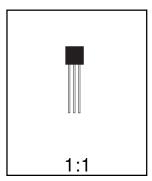


# **TO-92 Package Dimensions**



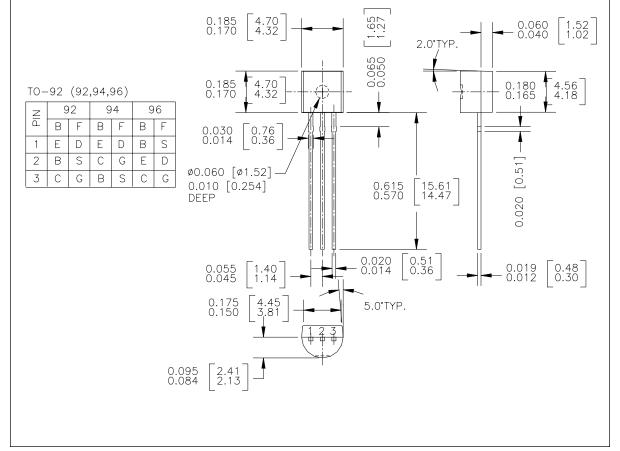
# TO-92 (FS PKG Code 92, 94, 96)





Scale 1:1 on letter size paper
Dimensions shown below are in:
inches [millimeters]

Part Weight per unit (gram): 0.1977



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